## NSN 5961-01-461-4153

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Inclosure Material:
Plastic
End Application:
Pathfinder class t-ags 60
Mounting Method:
Terminal
Semiconductor Material:
Lead sulfide
Voltage Rating In Volts Per Characteristic:
400.00 reverse voltage, dc and 400.00 repetitive peak reverse voltage and 400.00 working peak reverse voltage
Current Rating Per Characteristic:
0.30 amperes source cutoff current absolute or 0.80 amperes collector current, dc and 60.00 amperes forward current, dc nanoamperes
Terminal Type And Quantity:
2 printed circuit
Shelf Life:
N/a
Unit Of Measure:
- <del>-</del>
Demilitarization:
No
Fiig:
A110a0